NPN Epitaxial Planar Silicon Transistor



2SC5831

Driver Applications

Applications

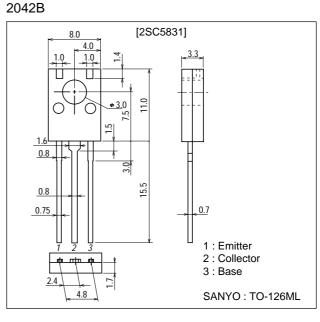
• Suitable for use in switching of inductive load (motor drivers, printer hammer drivers, relay drivers).

Features

- High DC current gain.
- Wide ASO.
- On-chip zener diode of 65±10V between collector and base.
- Uniformity in collector-to-base voltage.
- Large inductive load handling capability.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		*55	V
Collector-to-Emitter Voltage	VCEO		*55	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		2	А
Collector Current (Pulse)	ICP		4	А
Collector Dissipation	PC		1.5	W
		Tc=25°C	10	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		-55 to +150	°C

*: On-chip zener diode(65±10V)

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			2	mA
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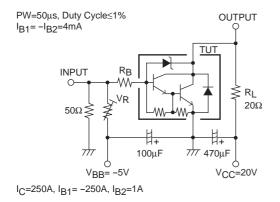
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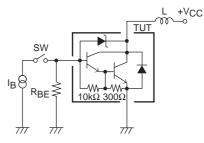
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
DC Current Gain	hFE	V _{CE} =5V, I _C =1A	1000	4000		
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =1A		180		MHz
Inductive Load	Es / b	L=100mH, RBE=100Ω	25			mJ
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =1A, I _B =4mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =1A, I _B =4mA			2.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=100μA, IE=0	55	65	75	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	55	65	75	V
Turn-ON Time	ton	See specified Test Circuit.		0.2		μs
Storage Time	tstg	See specified Test Circuit.		3.5		μs
Fall Time	tf	See specified Test Circuit.		0.5		μs

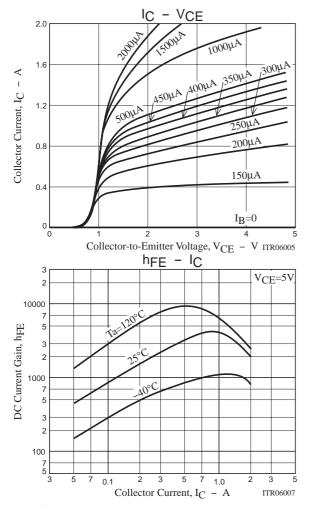
Switching Time Test Circuit

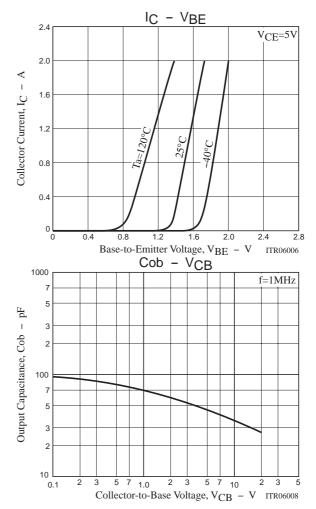


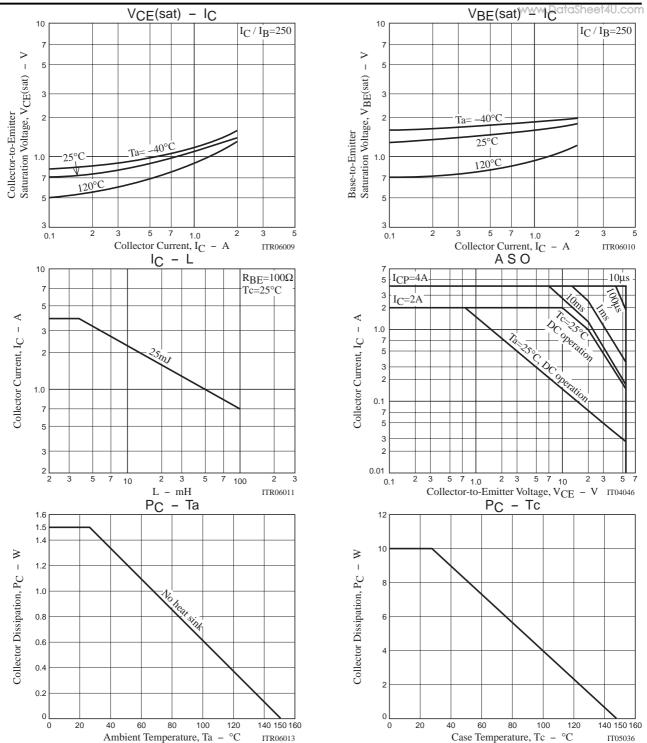
Es / b Test Circuit











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